# INT-A-PAK Power Module Thyristor/Diode, 300 A



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INT-A-PAK

PRIMARY CHARACTERISTICS					
I <sub>T(AV)</sub>	300 A				
Туре	Modules -thyristor, standard				
Package	INT-A-PAK				

#### **FEATURES**

- Electrically isolated base plate
- 3000 V<sub>RMS</sub> isolating voltage
- Industrial standard package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996 😱
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

- Battery chargers
- Welders
- Power converters
- Alternators

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
V <sub>DRM</sub> /V <sub>RRM</sub>		800	V		
I <sub>T(AV)</sub>	53 °C	300	А		
I <sub>T(RMS)</sub>		116	А		
	50 Hz	6500	۸		
ITSM	60 Hz	6900	A		
l <sup>2</sup> t	50 Hz	214	kA <sup>2</sup> s		
1-1	60 Hz	195	KA-S		
l²√t		2140	kA²√s		
TJ	Range	-40 to +140	°C		

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS							
TYPE NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> /V <sub>DSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> ∕I <sub>DRM</sub> AT 125 °C mA				
VS-VSKL300/08PbF	800	900	50				







PARAMETER	SYMBOL		TEST CONDITION	DNS	VALUES	UNITS	
Maximum average on-state current	I <sub>T(AV)</sub>	180° conducti	300	А			
at case temperature	-1(AV)				53	°C	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	As AC switch			116		
Maximum peak, one-cycle on-state, non-repetitive surge current		t = 10 ms	No voltage		6600		
		t = 8.3 ms	reapplied		6900	А	
	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>BBM</sub>		5500	1	
		t = 8.3 ms	reapplied	Sine half wave,	5800	1	
NA		t = 10 ms	No voltage	− initial T <sub>J</sub> = T <sub>J</sub> maximum	214	kA <sup>2</sup> s	
	12.	t = 8.3 ms	reapplied		195		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	100 % V <sub>BBM</sub>		151		
		t = 8.3 ms	reapplied		138		
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 1	2140	kA²√s			
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π x l	$T(AV) < I < \pi \times I_{T(AV)},$	T <sub>J</sub> maximum	0.796	.,	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}),$			0.868	V	
Low level value on-state slope resistance	r <sub>t1</sub>	(16.7 % x π x l	0.972				
High level value on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J$ maximum			0.88	mΩ	
	V <sub>TM</sub>	T 05 %0 1	500 A	SCR	1.35		
Maximum on-state voltage drop	V <sub>FM</sub>	– T <sub>J</sub> = 25 °C, I <sub>pk</sub> = 500 A		DIODE	1.20	V	

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Typical delay time	t <sub>d</sub>	Gate current 1 A, dI <sub>g</sub> /dt = 1 A/µs $V_d$ = 0.67 % $V_{DRM}$ , T <sub>J</sub> = 25 °C	1.0	110			
Typical turn-off time	tq	$I_{TM}$ = 300 A, $T_J$ = $T_J$ maximum, dI/dt = 20 A/µs, $V_R$ = 50 V dV/dt = 20 V/µs, Gate 0 V 100 $\Omega,$ $t_p$ = 500 µs	100	μs			

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum critical rate of rise of off-state voltage	dV/dt	$T_{J}$ = $T_{J}$ maximum linear to 67 $\%$ rated $V_{DRM}$	500	V/µs		
Maximum peak reverse and off-state leakage current	I <sub>DRM</sub> , I <sub>RRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	50	mA		
RMS insulation voltage	V <sub>INS</sub>	50 Hz, circuit to base, all terminal shorted, t = 1 s	3000	V		



TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	10.0	w			
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, f = 50 Hz, d% = 50	2.0	vv			
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	3.0	A			
Maximum required DC gate voltage to trigger	V <sub>GT</sub>		3	V			
Maximum required DC gate current to trigger	I <sub>GT</sub>	$T_J = 25 \text{ °C}$ Anode supply: 12 V resistive load	200	mA			
Maximum holding current	Ι <sub>Η</sub>		600				
Maximum peak positive gate voltage	+V <sub>GM</sub>	T = T maximum $t < 5$ ma	20	V			
Maximum peak negative gate voltage	-V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	5.0				
DC gate voltage not to trigger	V <sub>GD</sub>	$T_J = T_J maximum$	0.30	V			
DC gate current not to trigger	I <sub>GD</sub>	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	10	mA			
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega,t_r \leq 1~\mu s$ $T_J$ = $T_J$ maximum, anode voltage $\leq 80~\%~V_{DRM}$	1000	A/µs			

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating temperature range		TJ		-40 to +140	°C	
Maximum storage tempera	ature range	T <sub>Stg</sub>		-40 to +150		
Maximum thermal resistance, junction to case per junction		R <sub>thJC</sub>	DC operation	0.19	- K/W	
Maximum thermal resistance, case to heatsink per module		R <sub>thCS</sub>	Mounting surface smooth, flat and greased	0.035		
Mounting torque + 10.0/	IAP to heatsink		A mounting compound is recommended and	41.0	Nimo	
Mounting torque ± 10 %	busbar to IAP		the torque should be rechecked after a period	4 to 6	Nm	
A second s			of 3 hours to allow for the spread of the	500	g	
Approximate weight			compound. Lubricated threads.	17.8	OZ.	
Case style				INT-A-F	PAK	

DEVICES	SINUSOIDAL CONDUCTION AT T <sub>J</sub> MAXIMUM				RECTANGULAR CONDUCTION AT TJ MAXIMUM				UNITS		
	180°	120°	90°	<b>60</b> °	30°	180°	120°	<b>90</b> °	60°	<b>30</b> °	
VSKL300	0.019	0.022	0.028	0.041	0.068	0.013	0.023	0.031	0.043	0.069	K/W

Note

Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC



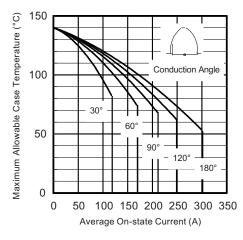


Fig. 1 - Current Ratings Characteristics

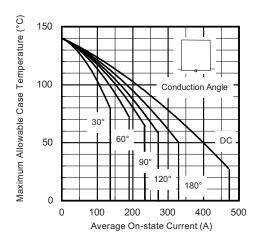


Fig. 2 - Current Ratings Characteristics

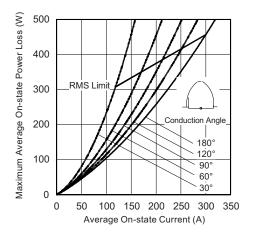


Fig. 3 - On-State Power Loss Characteristics

### VS-VSKL300/08PbF

### **Vishay Semiconductors**

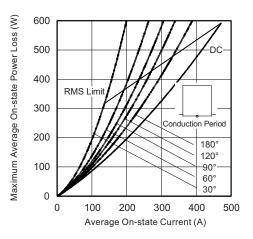


Fig. 4 - On-State Power Loss Characteristics

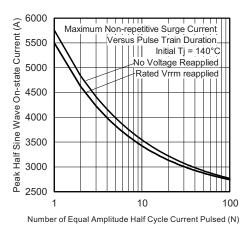


Fig. 5 - Maximum Non-Repetitive Surge Current

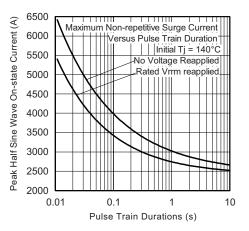


Fig. 6 - Maximum Non-Repetitive Surge Current

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 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
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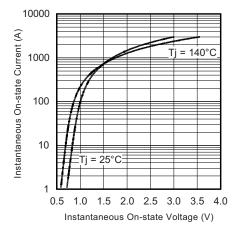


Fig. 7 - On-State Voltage Drop Characteristics (SCR)

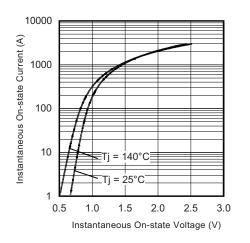


Fig. 8 - On-State Voltage Drop Characteristics (Diode)

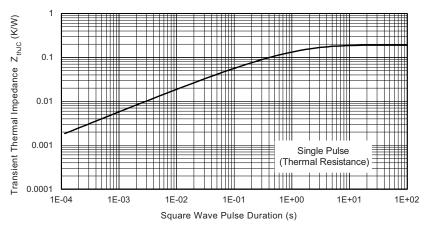
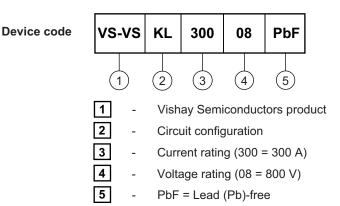


Fig. 9 - Thermal Impedance ZthJC Characteristics

#### **ORDERING INFORMATION TABLE**



VS-VSKL300/08PbF

### **Vishay Semiconductors**



CIRCUIT CONFIGURATION						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
SCR/diode doubler circuit, negative control	L					

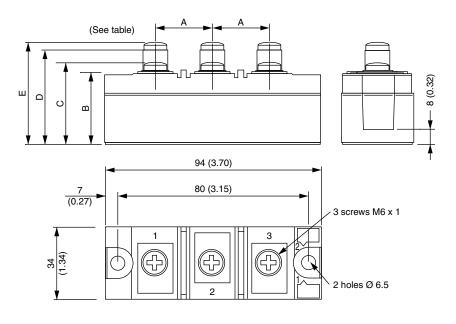
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95010			





# **INT-A-PAK Diode**

#### **DIMENSIONS** in millimeters (inches)



Α	В	С	D	E
23 (0.91)	30 (1.18)	36 (1.42)	-	-



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